

Engineering Development Model

RF Transformer

ADT1-ED9855/1

Impedance Ratio : 1

Important Note

This model has been designed, built and tested in our engineering department. Performance data represents model capability. At present it is a non-catalog model. On request, we can supply a final specification sheet, part number and price/delivery information.



Please click "Back", and then click "Contact Us" for Applications support.

CASE STYLE : CD636

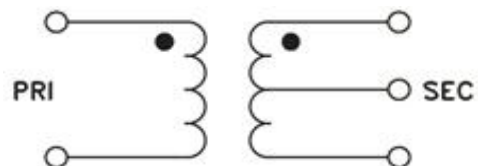
ELECTRICAL SPECIFICATIONS 50Ω @ +25°C					
Parameter		Min.	Typ.	Max.	Units
Frequency		3		1000	MHz
Insertion Loss *	3 dB Bandwidth		3 - 1000		MHz
	2 dB Bandwidth		4 - 500		MHz
	1 dB Bandwidth		5 - 350		MHz
Amplitude Unbalance	over 3dB Bandwidth		0.5		dB
	over 1dB Bandwidth		0.1		dB
Phase Unbalance	over 3dB Bandwidth		5.0		deg.
	over 1dB Bandwidth		1.00		deg.

Note:

* Insertion Loss is referenced to mid-band loss, 0.92dB typ.

MAXIMUM RATINGS	
Operating Temperature	-20°C to 85°C
Storage Temperature	-55°C to 100°C
RF Power	0.25 W
DC Current	30 mA

Configuration : A



PIN CONNECTIONS	
PRIMARY DOT	3
PRIMARY	1
SECONDARY DOT	4
SECONDARY	6
SECONDARY CT	5
ISOLATE	2